**Product data sheet** 

## 1. Product profile

## 1.1. General description

PNP medium power transistors in a medium power SOT223 (SC73) Surface-Mounted Device (SMD) plastic package.

**Table 1. Product overview** 

Type number	Package	NPN comlement	
	Nexperia	JEDEC	
BCP52T	SOT223	SC-73	BCP55T
BCP52-10T			BCP55-10T
BCP52-16T			BCP55-16T

### 1.2. Features and benefits

- High collector current capability I<sub>C</sub> and I<sub>CM</sub>
- · Three current gain selections
- · High power dissipation capability
- AEC-Q101 qualified

## 1.3. Applications

- · Linear voltage regulators
- MOSFET drivers
- · High-side switches
- · Power management
- Amplifiers

#### 1.4. Quick reference data

Table 2. Quick reference data

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	-60	V
I <sub>C</sub>	collector current		-	-	-1	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-	-2	Α



### 60 V, 1 A PNP medium power transistors

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$h_{FE}$	DC current gain						
	BCP52T	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -150 mA	[1]	63	-	250	
	BCP52-10T		[1]	63	-	160	
	BCP52-16T		[1]	100	-	250	

<sup>[1]</sup> pulsed;  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ 

## 2. Pinning information

#### Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	4	C
2	С	collector		B—
3	Е	emitter		, h
4	С	collector	☐1 ☐2 ☐3	Ë sym132

# 3. Ordering information

#### **Table 4. Ordering information**

Type number	Package					
	Name	Description	Version			
BCP52T	SC-73	plastic, surface-mounted package with increased heatsink;	SOT223			
BCP52-10T		4 leads				
BCP52-16T						

# 4. Marking

## Table 5. Marking

i abio o manang	
Type number	Marking code
BCP52T	BCP52T
BCP52-10T	P5210T
BCP52-16T	P5216T

#### 60 V, 1 A PNP medium power transistors

## 5. Limiting values

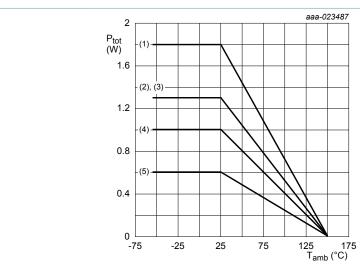
#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

T<sub>amb</sub> = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-60	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-60	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
I <sub>C</sub>	collector current			-	-1	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-2	Α
I <sub>B</sub>	base current			-	-0.2	Α
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-0.3	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	0.6	W
			[2]	-	1	W
			[3]	-	1.3	W
			[4]	-	1.3	W
			[5]	-	1.8	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>.
- [3] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 6 cm<sup>2</sup>.
- [4] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated and standard footprint.
- [5] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated; mounting pad for collector 1 cm.<sup>2</sup>



- (1) FR4 PCB; 4-layer copper; 1 cm<sup>2</sup>
- (2) FR4 PCB; single-sided copper; 6 cm<sup>2</sup>
- (3) FR4 PCB; 4-layer copper; standard footprint
- (4) FR4 PCB; single-sided copper; 1 cm<sup>2</sup>
- (5) FR4 PCB; single-sided copper; standard footprint

#### Fig. 1. Power derating curves

### 60 V, 1 A PNP medium power transistors

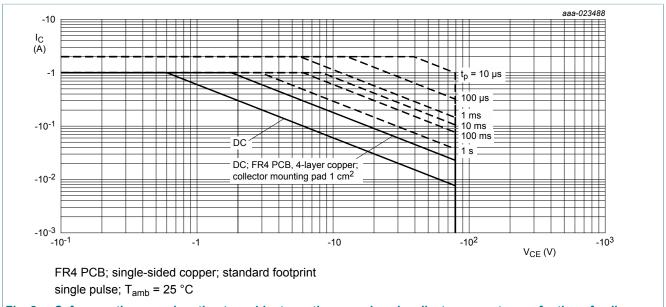


Fig. 2. Safe operating area; junction to ambient; continous and peak collector currents as a funtion of collecoremitter voltage

#### 60 V, 1 A PNP medium power transistors

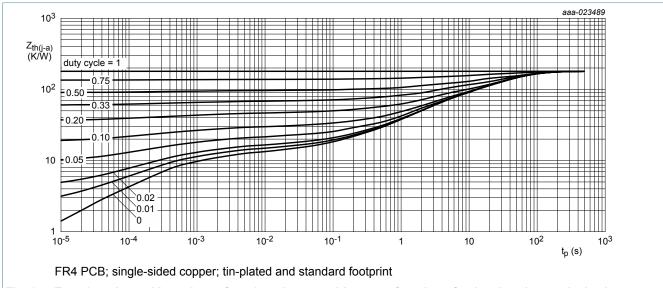
### 6. Thermal characteristics

#### **Table 7. Thermal characteristics**

 $T_{amb}$  = 25 °C unless otherwise specified.

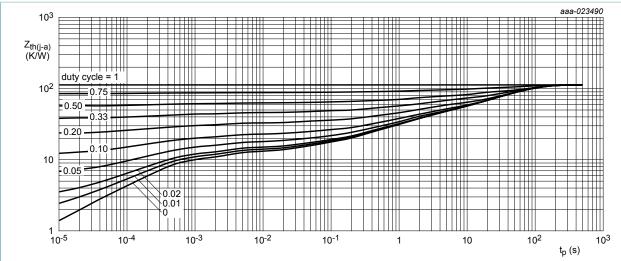
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub> thermal resistance from j	thermal resistance from junction to ambient	in free air	[1]	-	-	209	K/W
			[2]			125	K/W
			[3]			97	K/W
			[4]	-	-	97	K/W
			[5]	-	-	70	K/W
R <sub>(j-sp)</sub>	thermal resistance from junction to solder point			-	-	18	K/W

- Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>. Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 6 cm<sup>2</sup>. [3]
- Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated and standard footprint. [4]
- [5] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>.



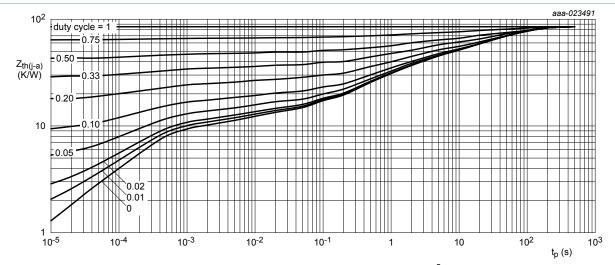
Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

#### 60 V, 1 A PNP medium power transistors



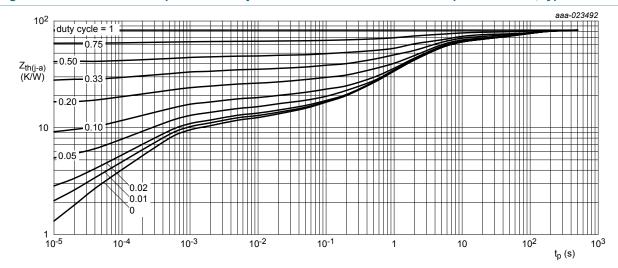
FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 6 cm<sup>2</sup>

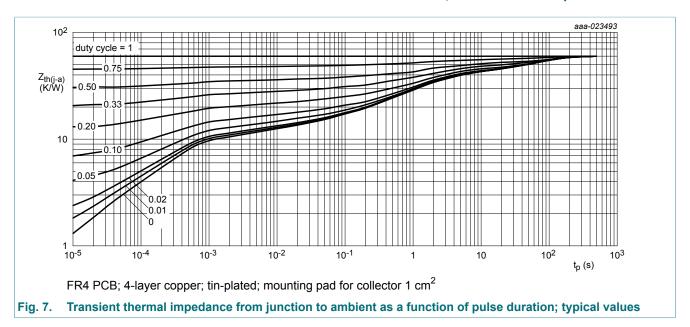
Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; 4-layer copper; tin-plated and standard footprint

Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

## 60 V, 1 A PNP medium power transistors



## 7. Characteristics

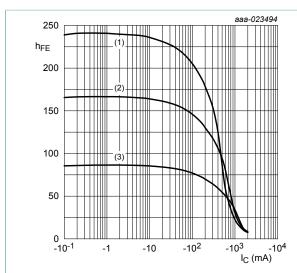
#### **Table 8. Characteristics**

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = -100 \ \mu A; I_E = 0 \ A$		-60	-		V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	I <sub>C</sub> = -2 mA; I <sub>E</sub> = 0 A		-60	-		V
V <sub>(BR)EBO</sub>	emitter-base breakdown voltage	I <sub>E</sub> = -100 μA; I <sub>C</sub> = 0 A		-5	-		V
I <sub>CBO</sub>	collector-base	V <sub>CB</sub> = -30 V; I <sub>E</sub> = 0 A		-	-	-100	nA
	cut-off current	$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$		-	-	-10	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A		-	-	-100	nA
h <sub>FE</sub> DC current gain			-				
BCP52T, -10T, -16	BCP52T, -10T, -16T	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -5 mA		63	-	-	
		V <sub>CE</sub> = -2 V; I <sub>C</sub> = -500 mA	[1]	40	-	-	
	BCP52T	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -150 mA	[1]	63	-	250	
	BCP52-10T	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -150 mA	[1]	63	-	160	
	BCP52-16T	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -150 mA	[1]	100	-	250	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -500 \text{ mA}; I_B = -50 \text{ mA}$	[1]	-	-	-500	mV
V <sub>BE</sub>	base-emitter voltage	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -500 mA	[1]	-	-	-1	V
f <sub>T</sub>	transition frequency	$V_{CE} = -5 \text{ V}; I_{C} = -50 \text{ mA}; f = 100 \text{ MHz}$		100	140	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$		-	7	-	pF

[1] pulsed;  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ 

### 60 V, 1 A PNP medium power transistors



$$V_{CE}$$
 = -2  $V$ 

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. DC current gain as a function of collector current; typical values

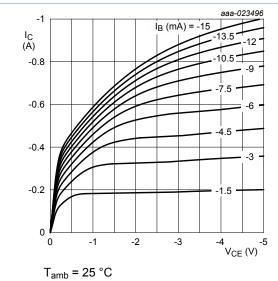
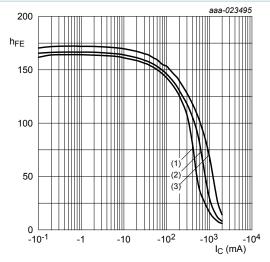


Fig. 10. Collector current as a function of collectoremitter voltage; typical values



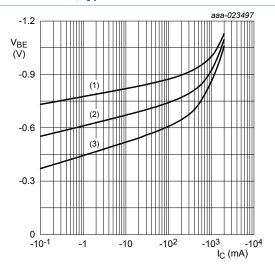
$$T_{amb} = 25 \, ^{\circ}C$$

(1) 
$$V_{CE} = -1 V$$

(2) 
$$V_{CE} = -2 V$$

(3) 
$$V_{CE} = -5 V$$

Fig. 9. DC current gain as a function of collector current; typical values



$$V_{CE} = -2 V$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

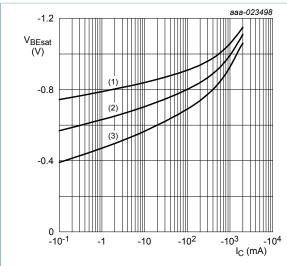
(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb}$$
 = 100 °C

Fig. 11. Base-emitter voltage as a function of collector current; typical values

8 / 14

### 60 V, 1 A PNP medium power transistors



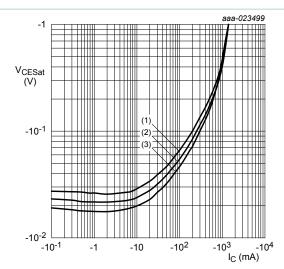
$$I_C/I_B = 10$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 12. Base-emitter saturation voltage as a function of Fig. 13. Collector-emitter saturation voltage as a collector current; typical values



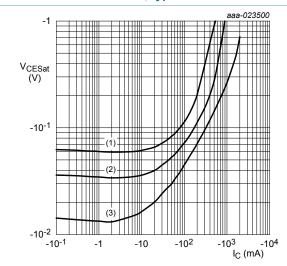
$$I_{\rm C}/I_{\rm B} = 10$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

function of collector current; typical values



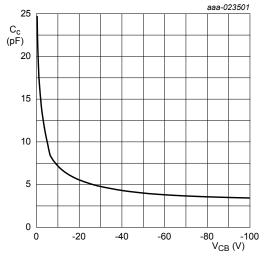
 $T_{amb}$  = 25 °C

$$(1) I_{\rm C}/I_{\rm B} = 50$$

(2) 
$$I_C/I_B = 20$$

(3)  $I_C/I_B = 5$ 

Fig. 14. Collector-emitter saturation voltage as a function of collector current; typical values

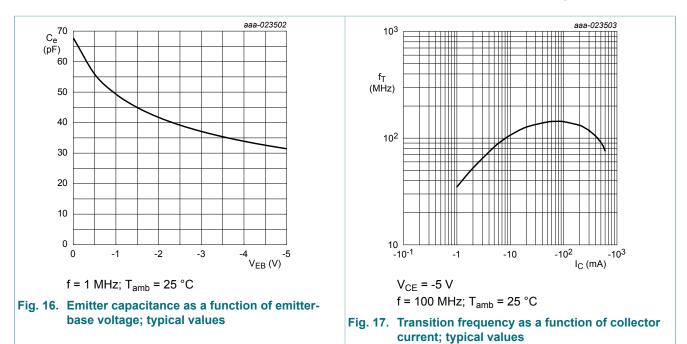


 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^{\circ}\text{C}$ 

Fig. 15. Collector capacitance as a function of collectorbase voltage; typical values

9 / 14

#### 60 V, 1 A PNP medium power transistors

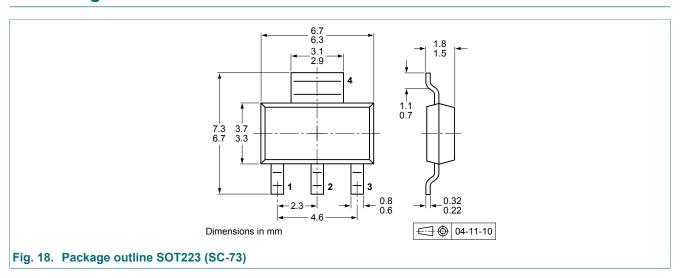


## 8. Test information

## 8.1. Quality information

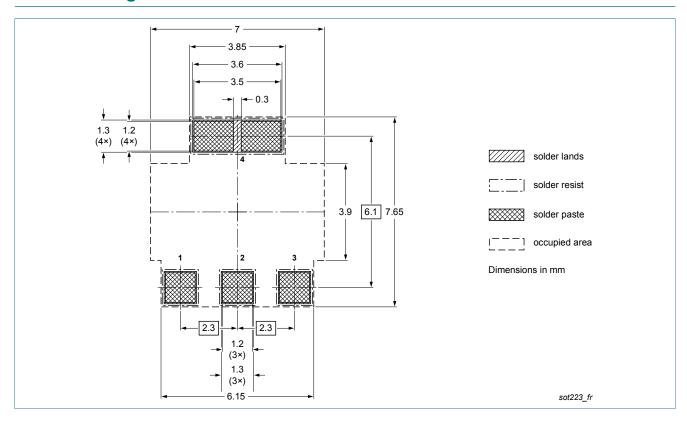
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

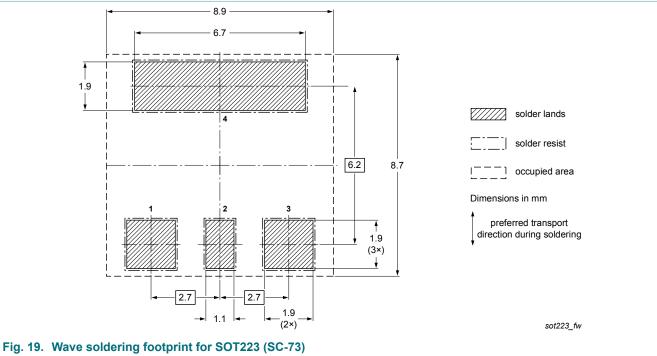
## 9. Package outline



### 60 V, 1 A PNP medium power transistors

# 10. Soldering





11 / 14

60 V, 1 A PNP medium power transistors

# 11. Revision history

#### Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BCP52T_SER v.1	20190429	Product data sheet	-	-

## 60 V, 1 A PNP medium power transistors

## 12. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <a href="https://www.nexperia.com">https://www.nexperia.com</a>.

#### **Definitions**

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

#### **Disclaimers**

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Suitability for use in automotive applications** — This Nexperia product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or

equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nexperia.com/profile/terms">http://www.nexperia.com/profile/terms</a>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

#### **Trademarks**

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Nexperia

# **BCP52T series**

## 60 V, 1 A PNP medium power transistors

## **Contents**

1. Product profile	1
1.1. General description	1
1.2. Features and benefits	1
1.3. Applications	1
1.4. Quick reference data	1
2. Pinning information	2
3. Ordering information	2
4. Marking	2
5. Limiting values	3
6. Thermal characteristics	5
7. Characteristics	7
8. Test information	10
8.1. Quality information	10
9. Package outline	10
10. Soldering	
11. Revision history	12
12. Legal information	13

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 29 April 2019

<sup>©</sup> Nexperia B.V. 2019. All rights reserved